

NVG, INC.

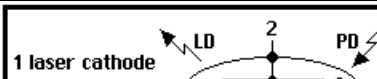
INFRARED LASER DIODES

Technical Data

MODEL # N780-5



INFRARED DIODE LASER ABSOLUTE MAXIMUM RATINGS - (Tc=25 °C)

TECHNICAL DATA - Index Guided MQW Structure - Wavelength: 780nm (Typ.) - Optical Power: 5mW CW - Threshold Current: 25mA (Typ.) - Standard Package: 5.6mm		1 laser cathode 2 common case 3 monitor diode anode 
Infrared light output	780nm	Pin Out Diagram
Optical power output	5mW CW	
Package Type	5.6mm	
Built-in photo diode for monitoring laser output		

Items	Symbols	Values	Unit
Optical output power	Po	5	mW
Laser diode reverse voltage	VLDR	2	V
Photo diode reverse voltage	VPDR	30	V
Operating temperature	Topr	-10 ~ +40	°C
Storage temperature	Tstg	-40 ~ +85	°C

OPTICAL and ELECTRICAL CHARACTERISTICS - (Tc=25 °C)

Items	Symbols	Min.	Typ.	Max.	Unit	Test Condition
Optical output power	Po	-	5	-	mW	-
Threshold current	Ith	15	25	40	mA	-
Operating current	Iop	25	35	50	mA	Po=5mW
Operating voltage	Vop	1.9	2.1	2.5	V	Po=5mW
Lasing wavelength	λ	770	780	790	nm	Po=5mW
Beam divergence	$\theta\Phi$	8	11	15	Deg	Po=5mW
Beam divergence	$\theta\zeta$	20	35	45	Deg	Po=5mW
Slope Efficiency (mW/mA)	η	0.1	0.3	0.6	-	-
Monitor current	Im	100	200	600	μ A	Po=5mW, VR=5V
Astigmatism	As	-	11	-	μ m	Po=5mW
MTTF			3-5,000 hrs.			Po=5mW, NA=0.4

Emitter Size	1 x 4 Microns
Emitter Distance to Cap Lens	0.3mm
Structure	Index Guided

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